

Diode Module

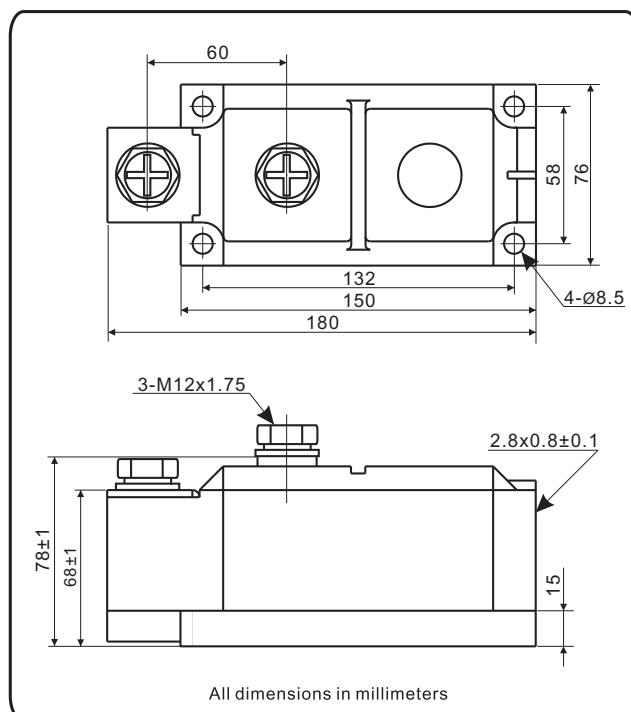
Features

1. NKE800 Series Diode modules are
Designed for various power controls
2. Voltage rating up to 1600V
3. Electrically isolated mounting base
4. Internal connections

Ordering code

NKE	800	/ xx
(1)	(2)	(3)

- (1) For Diode modules NKE
 (2) Maximum average forward current , A
 (3) Voltage code , V (code x 100 = / V_{RRM})



Electrical Characteristics

Parameter	Condition	Max. Value	Unit
I _{F(AV)}	Average forward current 180° half sine wave, 50 Hz, T _j =150°C Single side cooled, T _C =100°C	800	A
I _{F(RMS)}	R.M.S. Forward current Single side cooled, T _C =85°C, T _j =150°C	1256	A
V _{RRM}	Repetitive peak reverse voltage t _p =10 ms V _{RMS} =V _{RRM} x 1.1, T _j =150°C	600 to 1600	V
I _{RRM}	Repetitive peak reverse current V _R =V _{RRM} , T _j =150°C	40	mA
I _{FSM}	Peak one-cycle surge (non-repetitive forward current) 10 ms duration, T _j =150°C V _R =0.6 V _{RRM}	18	KA
I ² _t	Max. Permissible surge energy V _F =V _{RRM}	1650	A ² Sx10 ³
V _{FM}	Peak forward voltage drop I _{FM} =2400A, @ T _C =25°C	1.7	V
V _{F(T0)}	Forward conduction threshold voltage	0.75	V
r _t	Forward conduction slope resistance	0.34	mΩ
T _{stg}	Storage temperature range	-40 to 160	°C
R _{th(J-C)}	Thermal resistance Single side cooled	0.08	°C/W
W _t	Approximate weight	2300	g
T	Busbar to module (M 10) A mounting compound is recommended. Torque should be rechecked after a period of 3 hours.	60	Kg-CM
	Module to heatsink (M 6)	30	Kg-CM

Fig. 1
Peak On-state Voltage Vs Peak On-state Current

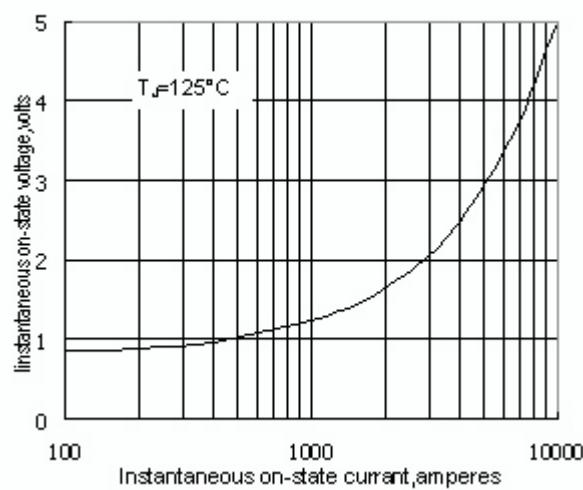


Fig. 3
Max Power Dissipation Vs. Mean On-state Current

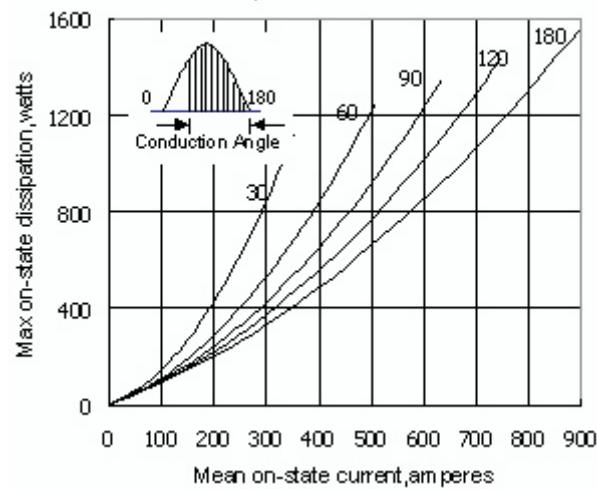


Fig.5
Max Power Dissipation Vs. Mean On-state Current

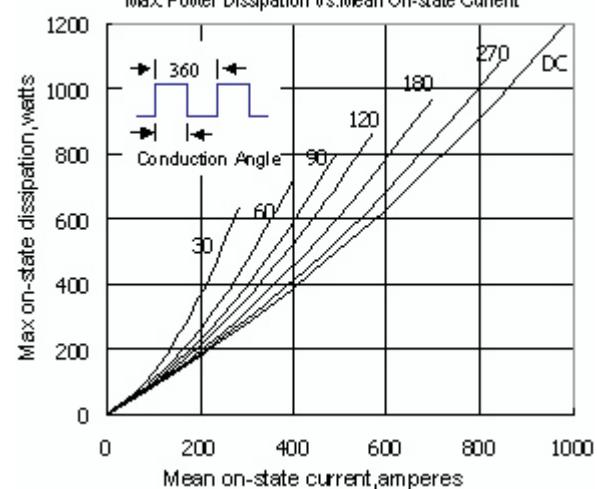


Fig. 2
Max junction To case Thermal Impedance Vs. Time

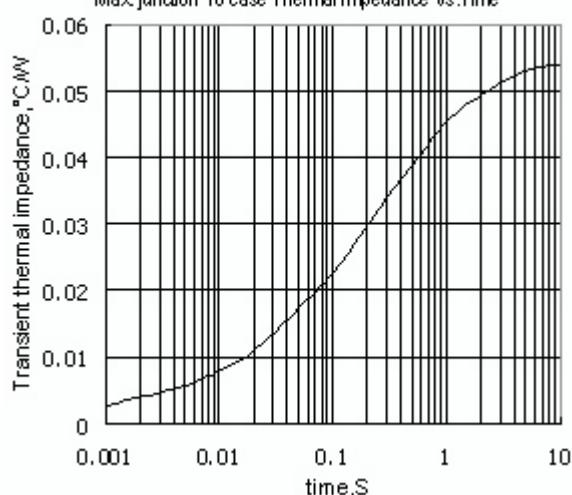


Fig. 4
Max case Temperature Vs. Mean On-state Current

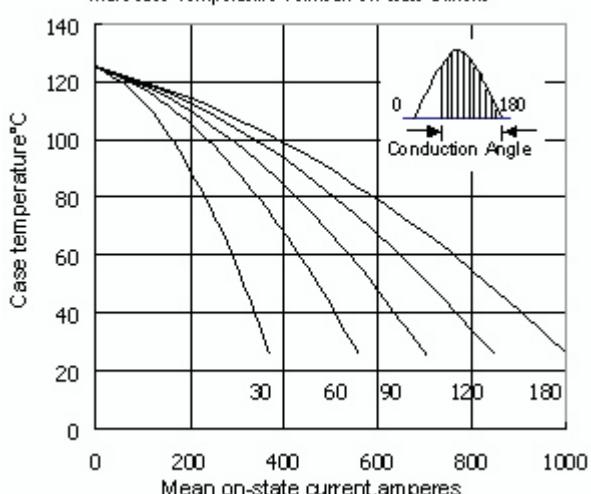


Fig. 6
Max case Temperature Vs. Mean On-state Current

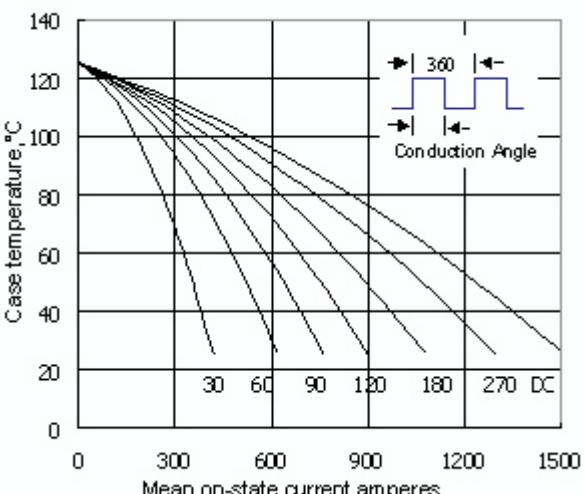


Fig. 7

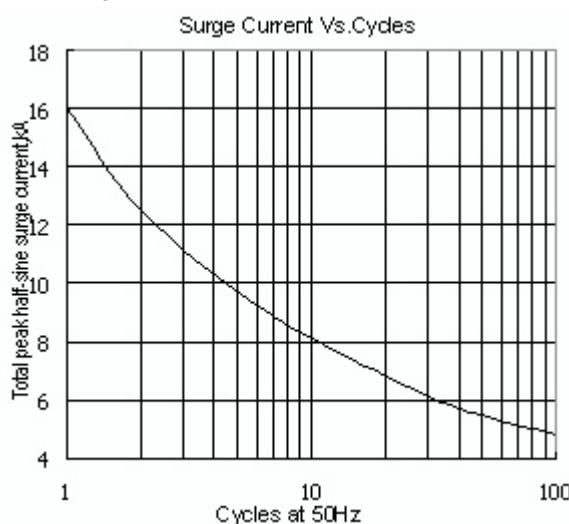


Fig. 8

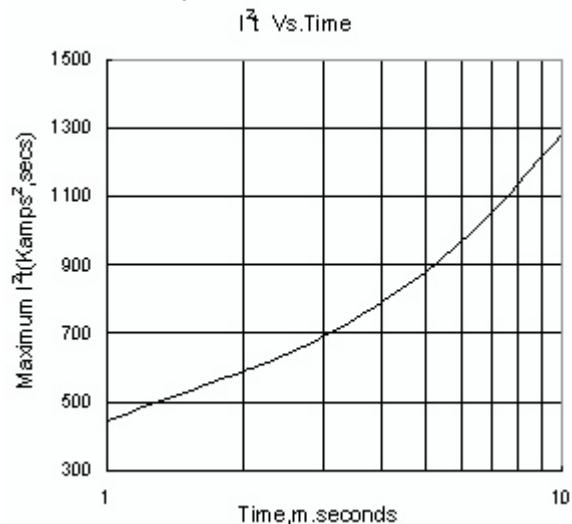


Fig. 9

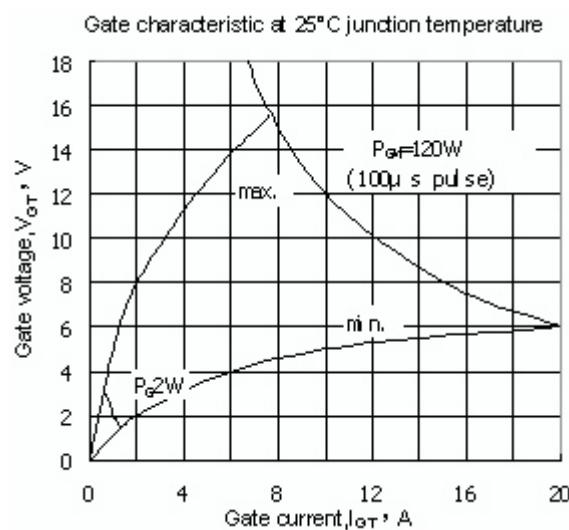


Fig. 10

